15	SDIO_DATA_3	I/O	SDIO data line 3
16	SDIO_DATA_CMD	I/O	SDIO command line
17	SDIO_DATA_CLK	I/O	SDIO CLK line
18	SDIO_DATA_0	I/O	SDIO data line 0
19	SDIO_DATA_1	I/O	SDIO data line 1
20	GND	—	Ground connections
21	VIN_LDO_OUT	P	Internal Buck voltage generation pin
22	VDDIO	P	I/O Voltage supply input
23	VIN_LDO	P	Internal Buck voltage generation pin
24	LPO	I	External Low Power Clock input (32.768KHz)
25	PCM_OUT	I/O	PCM Data output
26	PCM_CLK	I/O	PCM Clock
27	PCM_IN	I/O	PCM data input
28	PCM_SYNC	I/O	PCM sync signal
29	WL_VDD_TCXO	P	1.7V to 3.3V supply for the TCXO driver
30	TCXO_IN	I	Reference clock input
31	GND	—	Ground connections
32	NC	—	Floating (Don’t connected to ground)
33	GND	—	Ground connections
34	BT_RST_N	I	Low asserting reset for Bluetooth core
35	NC	—	Floating (Don’t connected to ground)
36	GND	—	Ground connections
37	BT_XTAL_IN	I	Crystal input for BT
38	BT_XTAL_OUT	O	Crystal output for BT
39	NC	—	Floating (Don’t connected to ground)
40	NC	—	Floating (Don’t connected to ground)
41	UART_RTS_N	O	Bluetooth UART interface
42	UART_TXD	O	Bluetooth UART interface
43	UART_RXD	I	Bluetooth UART interface
44	UART_CTS_N	I	Bluetooth UART interface
45	TP1 (NC)	—	Floating (Don’t connected to ground)
46	TP2 (NC)	—	Floating (Don’t connected to ground)
47	TP3 (NC)	—	Floating (Don’t connected to ground)

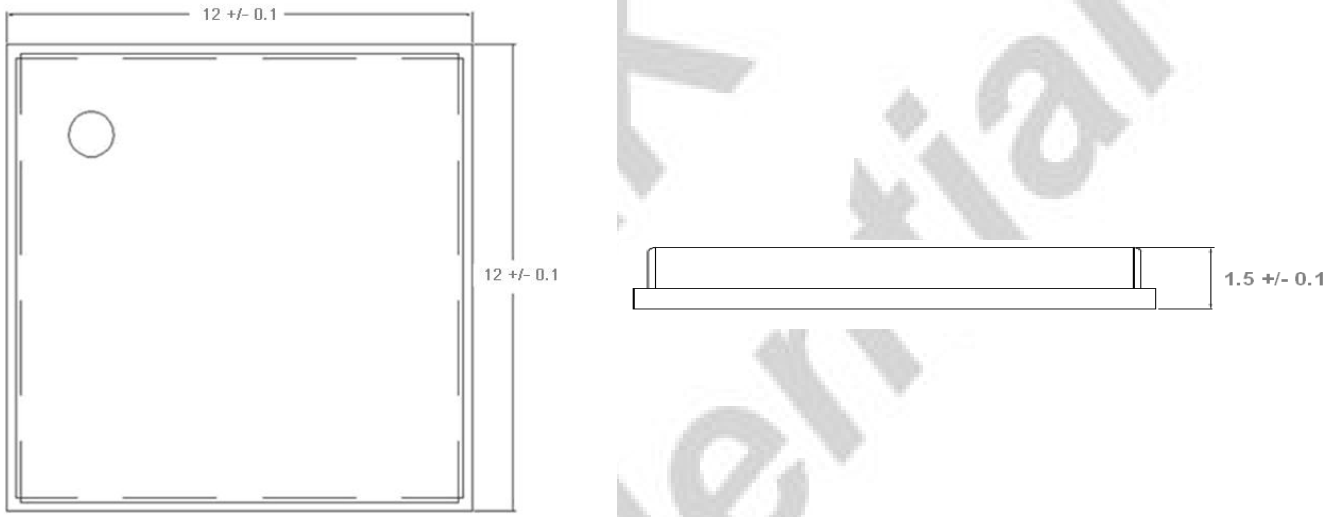
8. Dimensions

8.1 Physical Dimensions

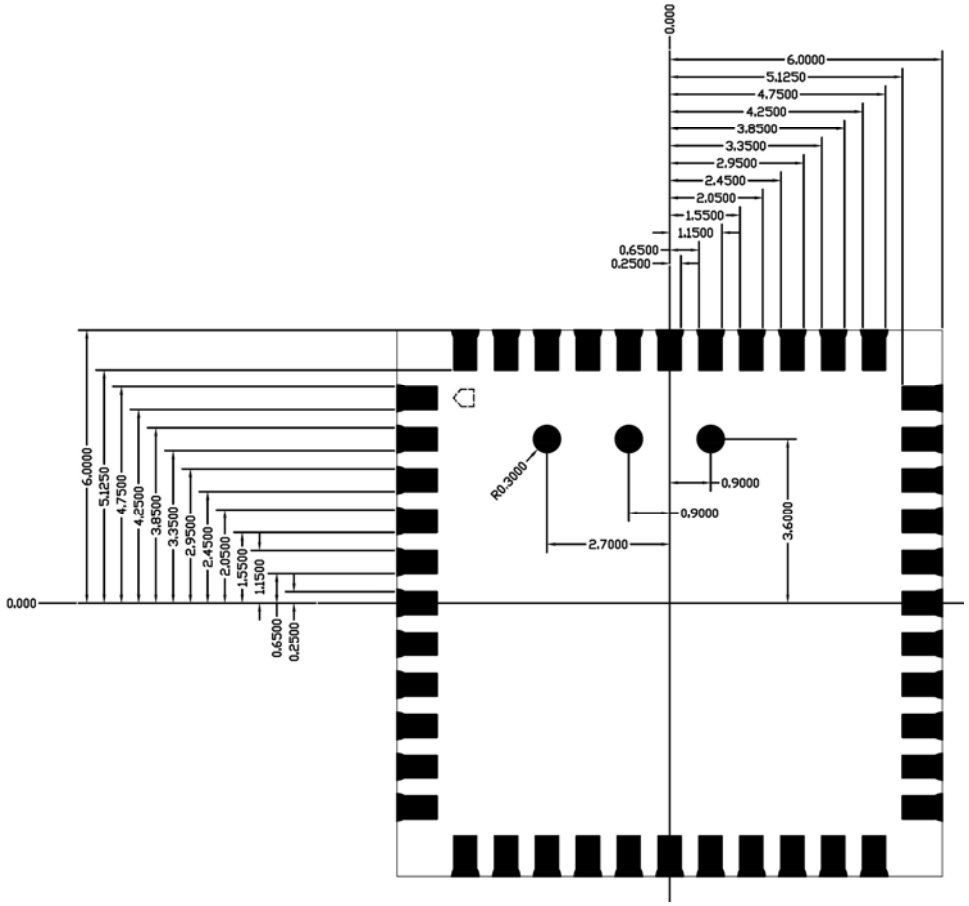
(Unit: mm)

< TOP VIEW >

< Side View >



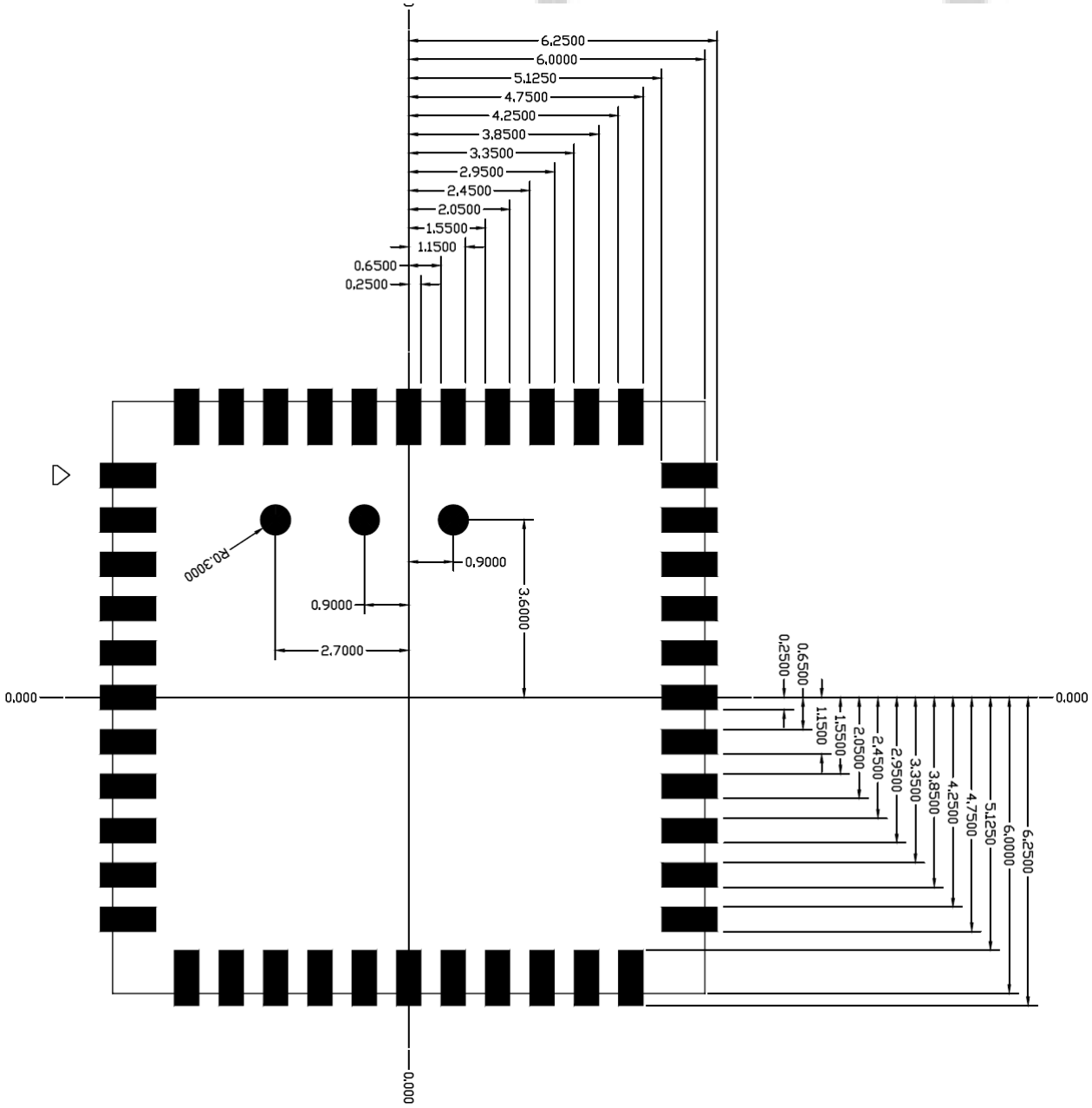
< TOP VIEW >



8.2 Layout Recommendation

(Unit: mm)

< TOP VIEW >



9. External clock reference

External LPO signal characteristics

Parameter	Specification	Units
Nominal input frequency	32.768	kHz
Frequency accuracy	±30	ppm
Duty cycle	30 - 70	%
Input signal amplitude	1600 to 3300	mV, p-p
Signal type	Square-wave or sine-wave	-
Input impedance	>100k <5	Ω pF
Clock jitter (integrated over 300Hz – 15KHz)	<1	Hz
Output high voltage	0.7Vio - Vio	V

External Ref_CLK signal characteristics

No.	Item	Symb.	Electrical Specification				Remark
			Min.	Type	Max.	Units	
1	Nominal Frequency	F0		26.00000		MHz	
2	Mode of Vibration			Fundamental			
3	Frequency Tolerance	ΔF/F0	-10	-	10	ppm	at 25℃±3℃
4	Operating Temperature Range	T_{OPR}	-30	-	85	℃	
5	Frequency Stability	TC	-10	-	10	ppm	
6	Storage Temperature	T_{STG}	-55	-	125	℃	
7	Load capacitance	CL	-	16		pF	
8	Equivalent Series Resistance	ESR	-	-	50	Ω	
9	Drive Level	DL	-	100	200	μW	
10	Insulation Resistance	IR	500	-	-	MΩ	At $100V_{DC}$
11	Shunt Capacitance	C0	-	-	3	pF	
12	Aging Per Year	Fa	-2	-	2	ppm	First Year

9.1 SDIO Pin Description

The module supports SDIO version 2.0 for 4-bit modes It has the ability to stop the SDIO clock and map the interrupt signal into a GPIO pin. This ‘out-of-band’ interrupt signal notifies the host when the WLAN device wants to turn on the SDIO interface. The ability to force the control of the gated clocks from within the WLAN chip is also provided.

- ❖ Function 0 Standard SDIO function (Max BlockSize / ByteCount = 32B)
- ❖ Function 1 Backplane Function to access the internal System On Chip (SOC) address space (Max BlockSize / ByteCount = 64B)
- ❖ Function 2 WLAN Function for efficient WLAN packet transfer through DMA (Max BlockSize/ByteCount=512B)

SDIO Pin Description

SDIO 4-Bit Mode	
DATA0	Data Line 0
DATA1	Data Line 1 or Interrupt
DATA2	Data Line 2 or Read Wait
DATA3	Data Line 3
CLK	Clock
CMD	Command Line

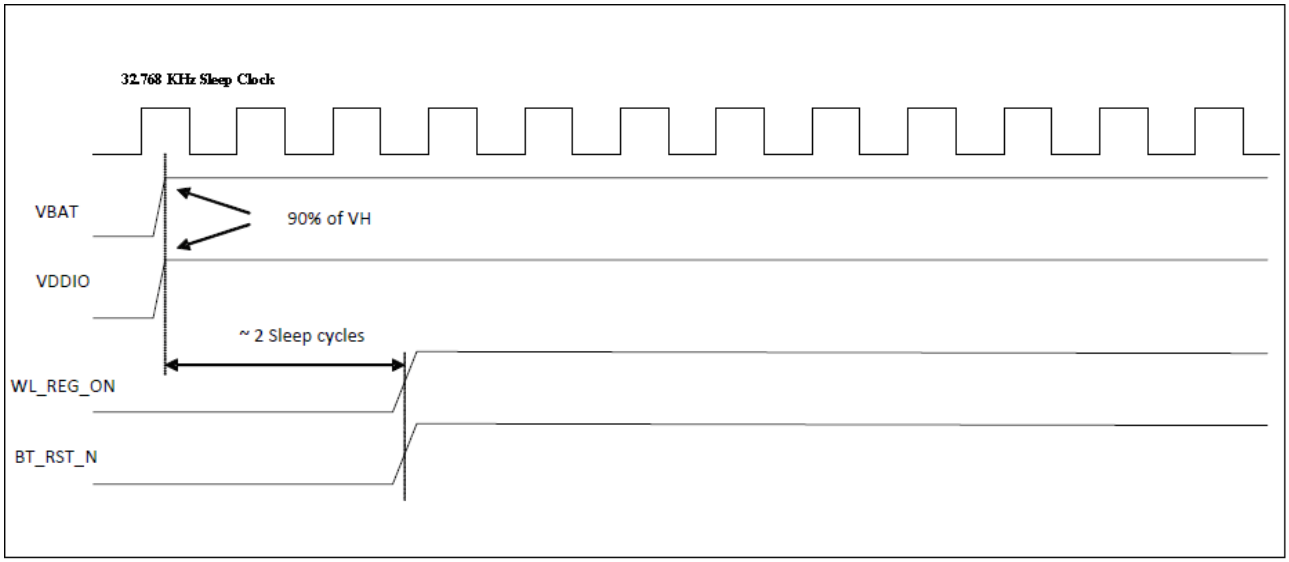
10. Host Interface Timing Diagram

10.1 Power-up Sequence Timing Diagram

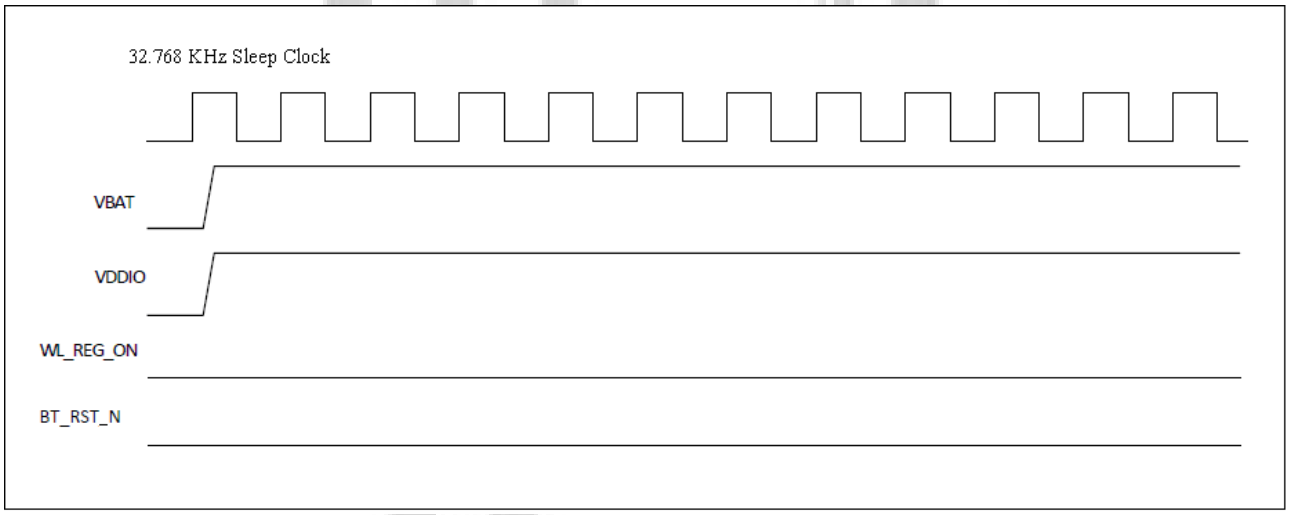
The module has two signals that allow the host to control power consumption by enabling or disabling the Bluetooth, WLAN and internal regulator blocks. These signals are described below.

Additionally, diagrams are provided to indicate proper sequencing of the signals for carious operating states. The timing value indicated are minimum required values: longer delays are also acceptable.

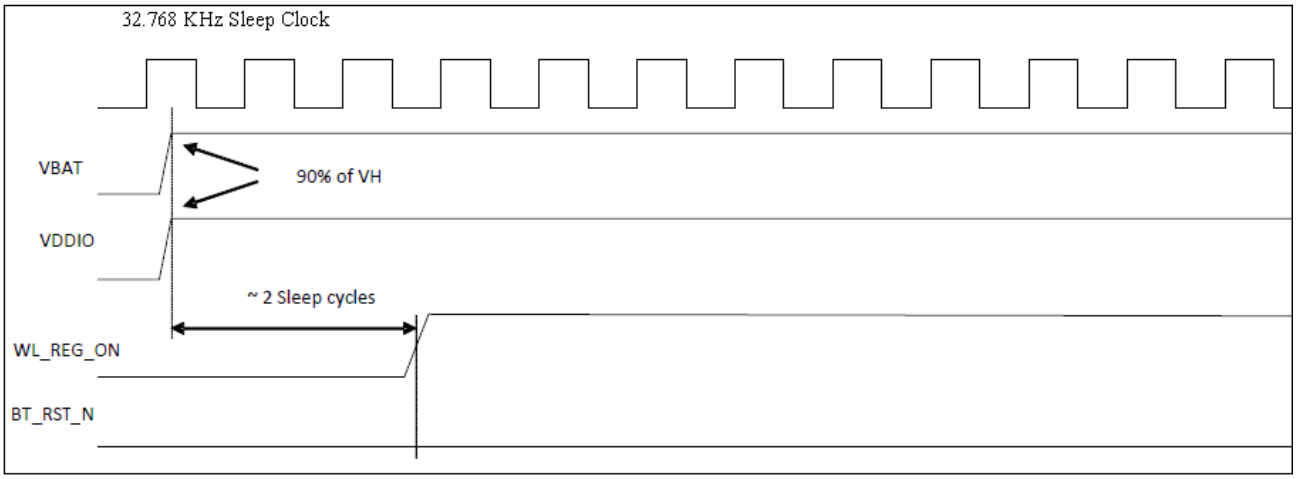
- ※ WL_REG_ON: Used by the PMU to power up the WLAN section. It is input to control the internal WLAN regulators. When this pin is high, the regulators are enabled and the WLAN section is out of reset. When this pin is low the WLAN section is in reset.
- ※ BT_RST_N: Used by the PMU to power up the internal Bluetooth regulators. If the BT_RST_N pins are low, the regulators are disabled.



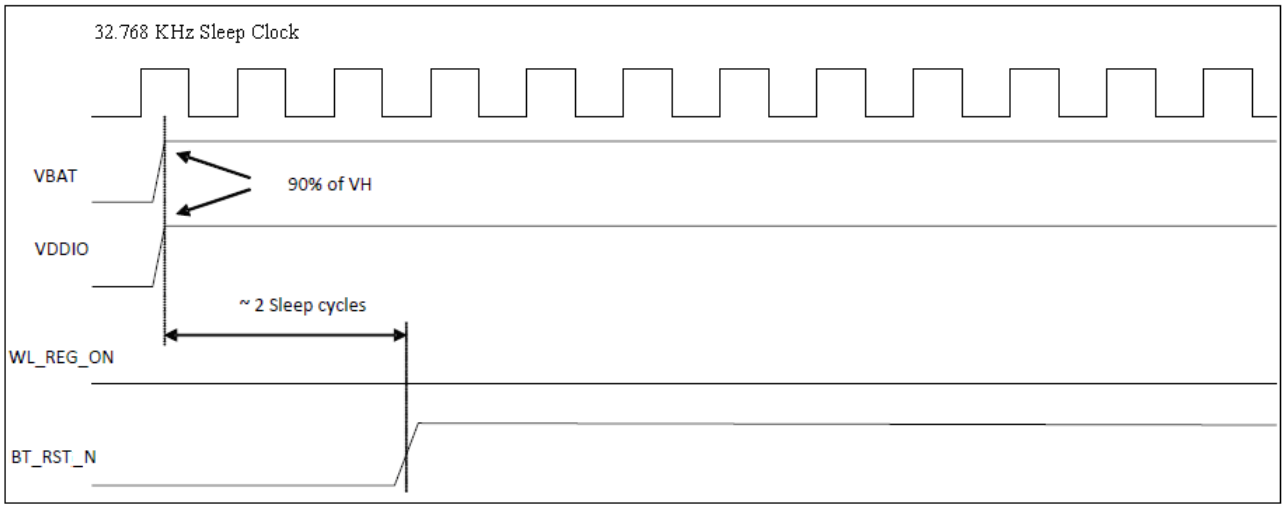
WLAN=ON, Bluetooth =ON



WLAN=OFF, Bluetooth =OFF

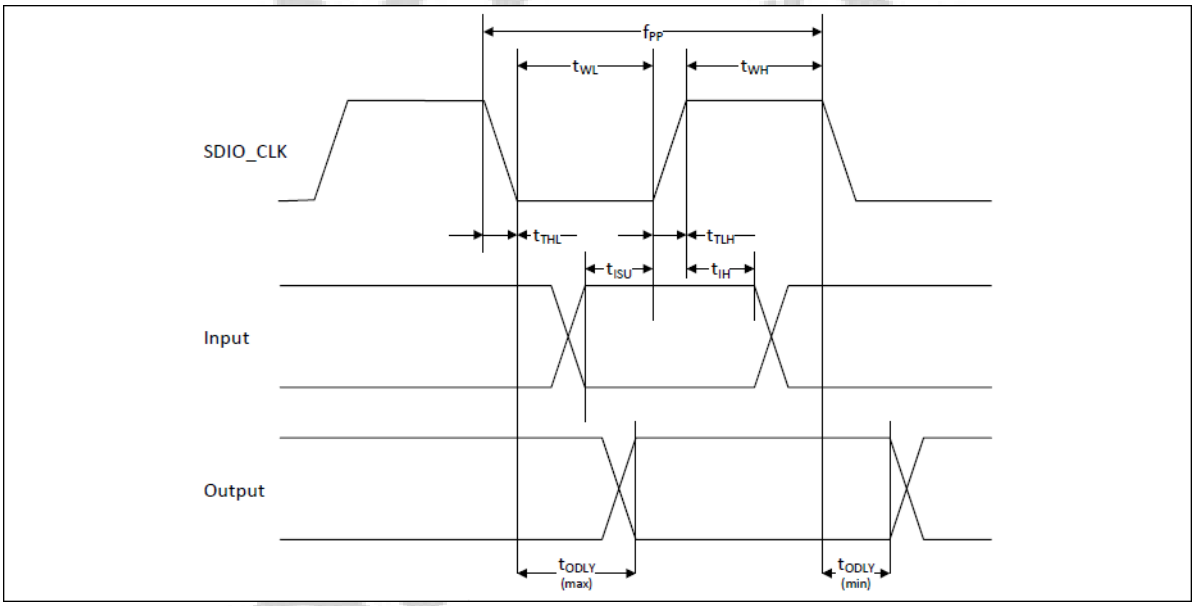


WLAN=ON, Bluetooth =OFF



WLAN=OFF, Bluetooth=ON

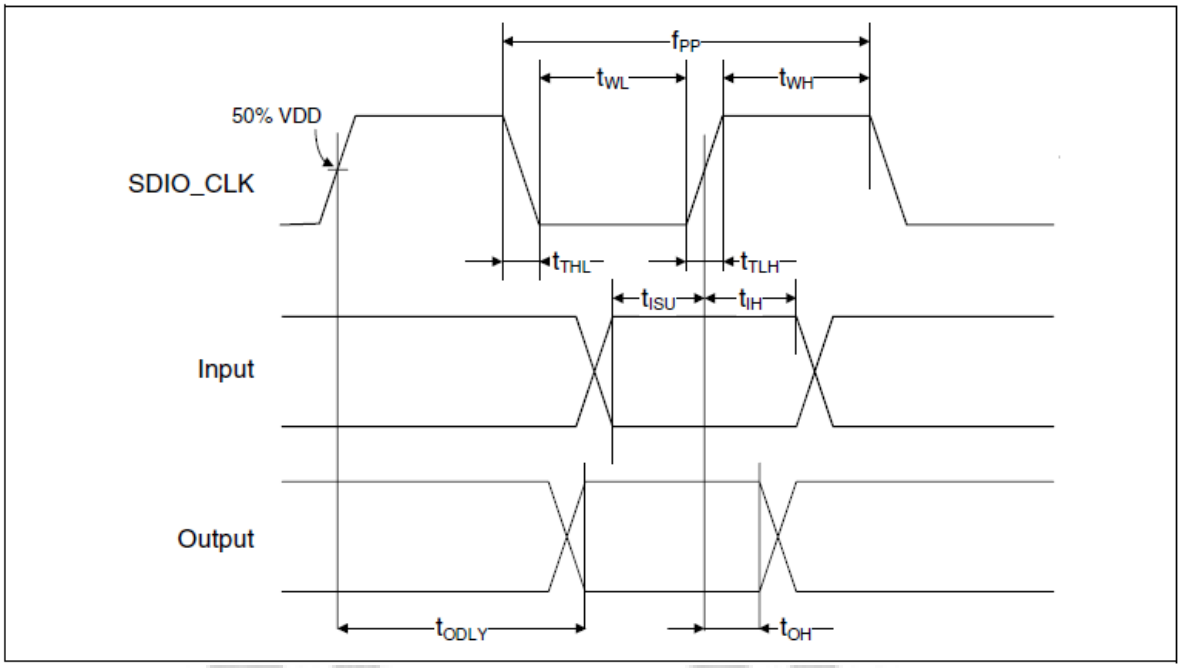
10.2 SDIO Default Mode Timing Diagram



Parameter	Symbol	Minimum	Typical	Maximum	Unit
SDIO CLK (All values are refferred to minimum VIH and maximum VIL[b])					
Frequency-Data Transfer mode	fPP	0	-	25	MHz
Frequency-Identification mode	fOD	0	-	400	kHz
Clock low time	tWL	10	-	-	ns
Clock high time	tWH	10	-	-	ns
Clock rise time	tTLH	-	-	10	ns
Clock low time	tTHL	-	-	10	ns
Inputs: CMD, DAT (referenced to CLK)					
Input setup time	tISU	5	-	-	ns
Input hold time	tIH	5	-	-	ns
Outputs: CMD, DAT (referenced to CLK)					
Output delay time – Data Transfer mode	tODLY	0	-	14	ns
Output delay time – Identification mode	tODLY	0	-	50	ns

a. Timing is based on CL ≤ 40pF load on CMD and Data.
b. min(Vih) = 0.7 x VDDIO and max(Vil) = 0.2 x VDDIO.

10.3 SDIO High Speed Mode Timing Diagram



Parameter	Symbol	Minimum	Typical	Maximum	Unit
SDIO CLK (All values are refferred to minimum VIH and maximum VIL[b])					
Frequency-Data Transfer mode	fPP	0	-	50	MHz
Frequency-Identification mode	fOD	0	-	400	kHz
Clock low time	tWL	7	-	-	ns
Clock high time	tWH	7	-	-	ns
Clock rise time	tTLH	-	-	3	ns
Clock low time	tTHL	-	-	3	ns
Inputs: CMD, DAT (referenced to CLK)					
Input setup time	tISU	6	-	-	ns
Input hold time	tIH	2	-	-	ns
Outputs: CMD, DAT (referenced to CLK)					
Output delay time – Data Transfer mode	tODLY	-	-	14	ns
Output hold time	tOH	2.5	-	-	ns
Total system capacitance (each line)	CL	-	-	40	pF

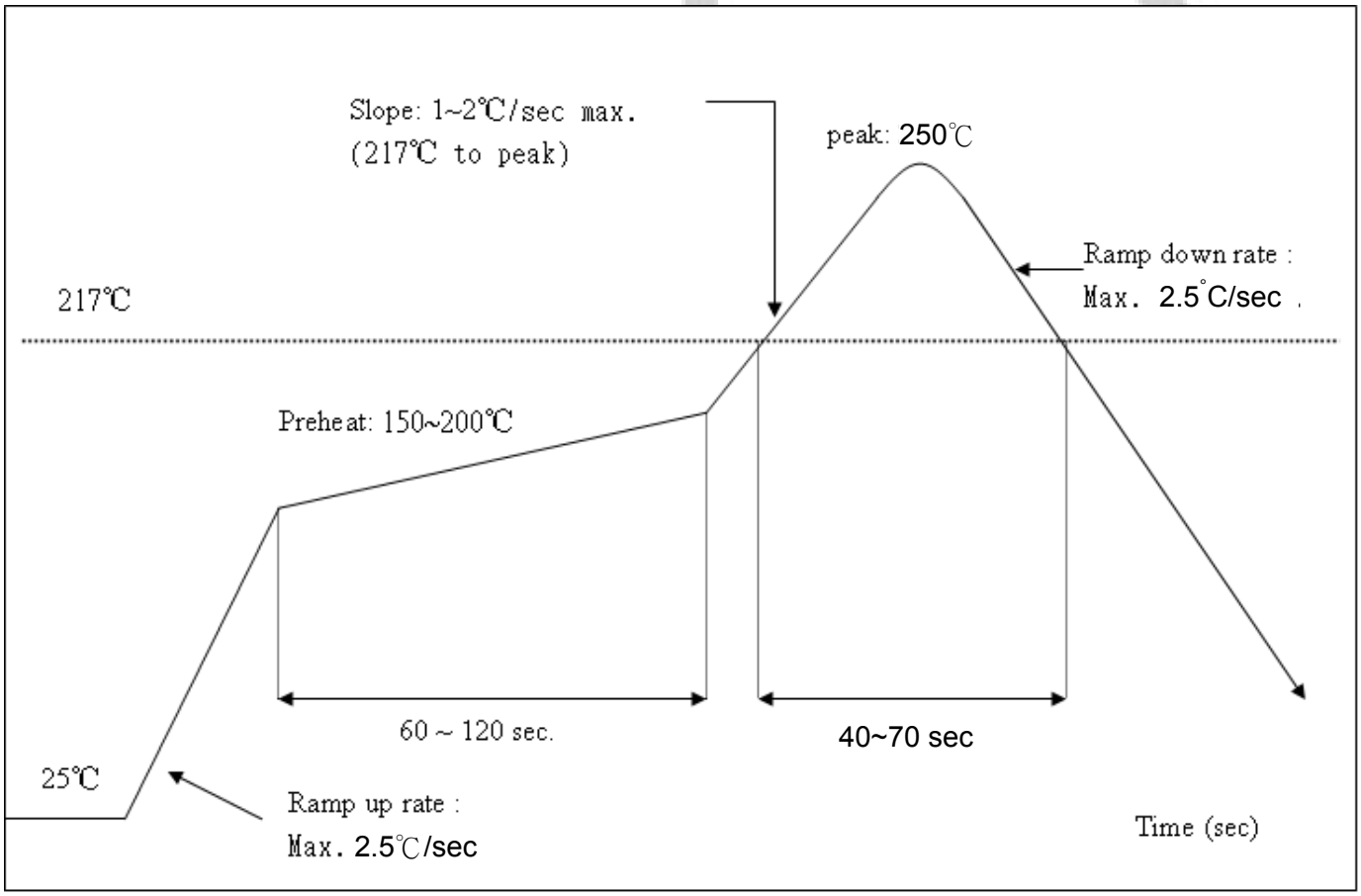
a. Timing is based on CL ≤ 40pF load on CMD and Data.
b. min(Vih) = 0.7 x VDDIO and max(Vil) = 0.2 x VDDIO.

11. Recommended Reflow Profile

Referred to IPC/JEDEC standard.

Peak Temperature : <250°C

Number of Times : ≤2 times

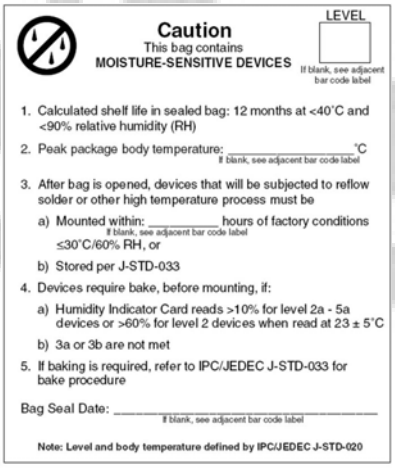


12. Package Information

12.1Label

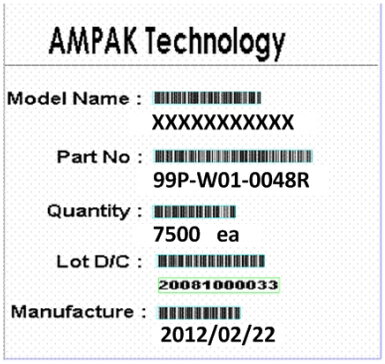
Label A→ Anti-static and humidity notice

Label B→ MSL caution / Storage Condition

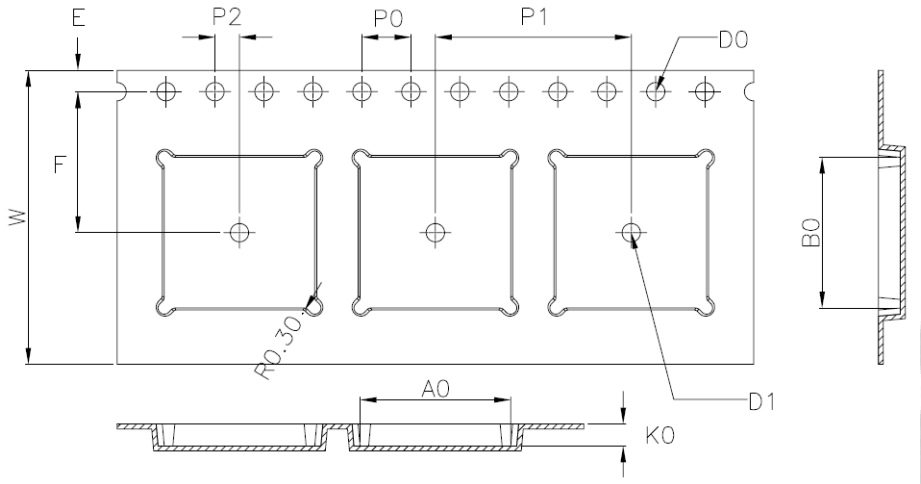


Label C→ Inner box label .

Label D→ Carton box label .

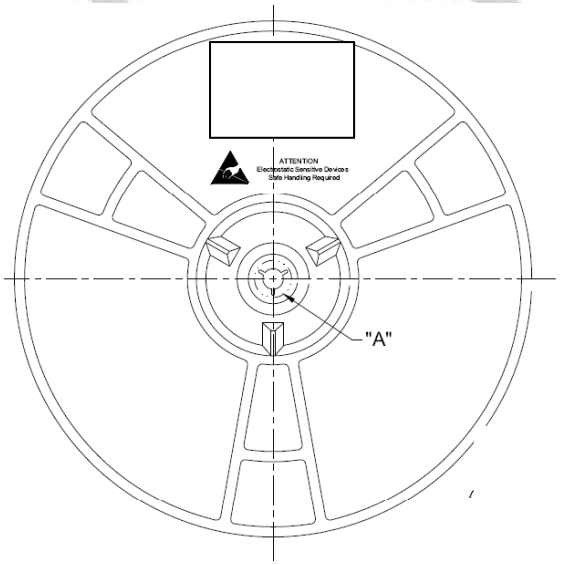


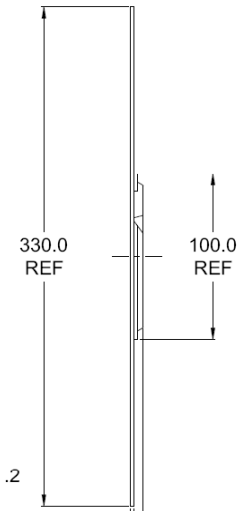
12.2 Dimension

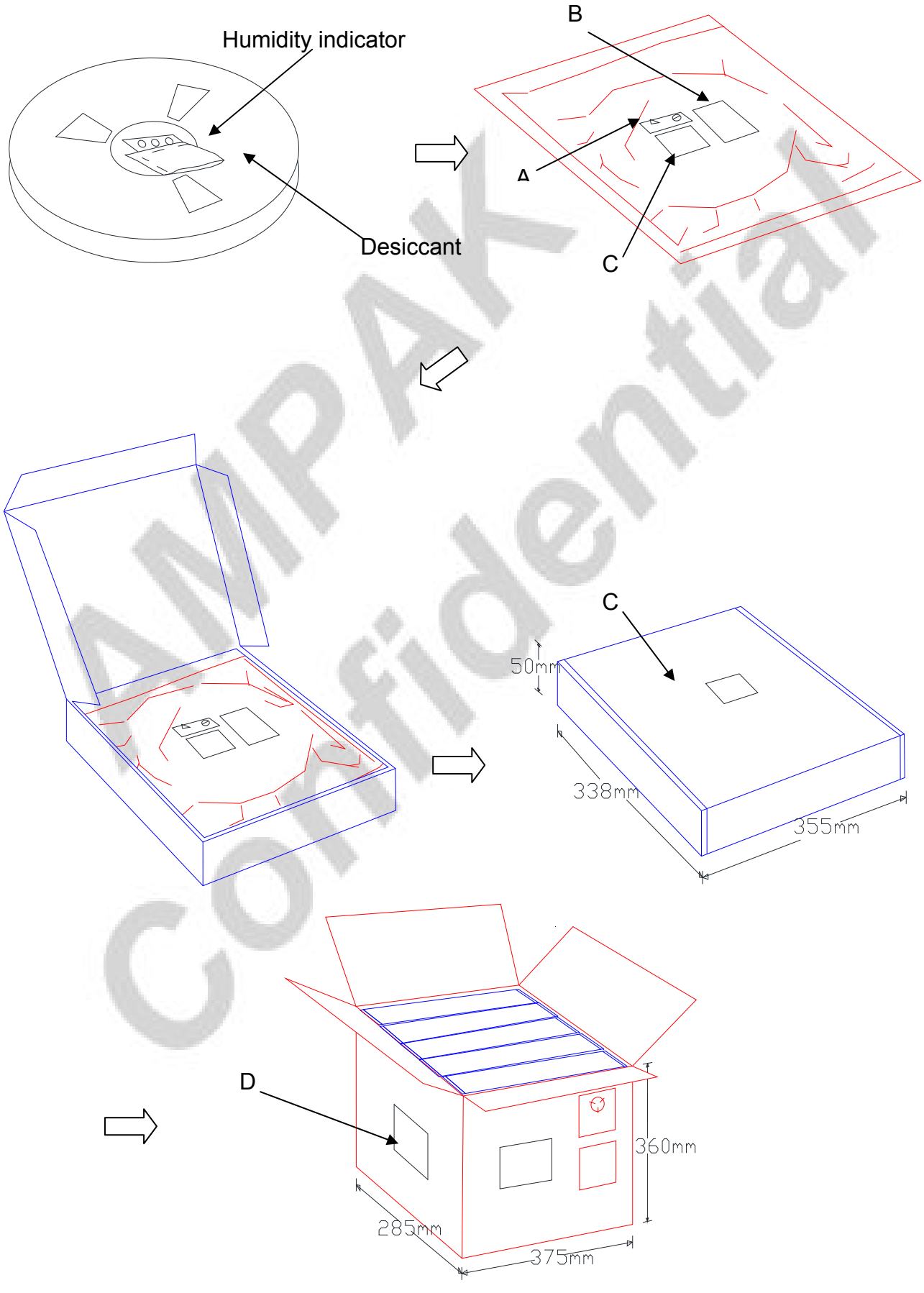


W	24.00±0.30
A0	12.30±0.10
B0	12.30±0.10
K0	1.80±0.10
E	1.75±0.10
F	11.50±0.10
P0	4.00±0.10
P1	16.00±0.10
P2	2.00±0.10
D0	1.50 $^{+0.10}_{-0.00}$
D1	ø1.50MIN

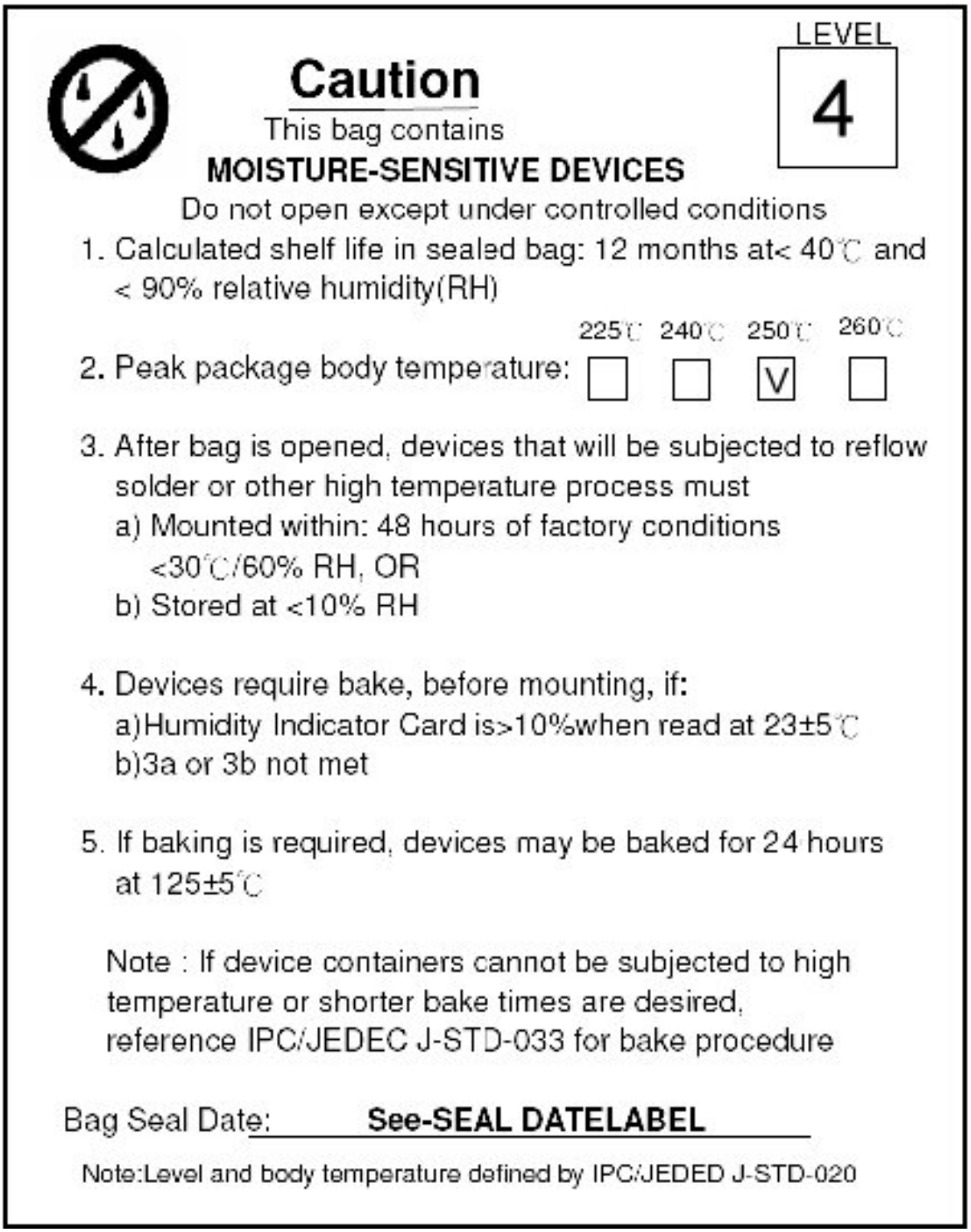
1. 10 sprocket hole pitch cumulative tolerance ±0.20.
2. Carrier camber is within 1 mm in 250 mm.
3. Material : Black Conductive Polystyrene Alloy.
4. All dimensions meet EIA-481-D requirements.
5. Thickness : 0.30±0.05mm.
6. Packing length per 22" reel : 98.5 Meters.(1:3)
7. Component load per 13" reel : 1500 pcs.







12.3 MSL Level / Storage Condition



Caution

This bag contains

MOISTURE-SENSITIVE DEVICES

Do not open except under controlled conditions

LEVEL 4

1. Calculated shelf life in sealed bag: 12 months at< 40℃ and < 90% relative humidity(RH)
2. Peak package body temperature: 225℃ ☐ 240℃ ☐ 250℃ ☑ 260℃ ☐
3. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must
   a) Mounted within: 48 hours of factory conditions <30℃/60% RH, OR
   b) Stored at <10% RH
4. Devices require bake, before mounting, if:
   a) Humidity Indicator Card is>10%when read at 23±5℃
   b) 3a or 3b not met
5. If baking is required, devices may be baked for 24 hours at 125±5℃

Note : If device containers cannot be subjected to high temperature or shorter bake times are desired, reference IPC/JEDEC J-STD-033 for bake procedure

Bag Seal Date: **See-SEAL DATELABEL**

Note:Level and body temperature defined by IPC/JEDED J-STD-020

※NOTE : Accumulated baking time should not exceed 96hrs